



R&T BiCMOS

Low Noise, Cryogenic Differential Amplifier

Prepared by: Bao TON

DESCRIPTION

The RH6200 is an ultralow noise, rail-to-rail input and output unity-gain stable op amp that features $0.95\text{nV}/\sqrt{\text{Hz}}$ noise voltage. This amplifier combines very low noise with a 165MHz gain bandwidth, $50\text{V}/\mu\text{s}$ slew rate and is optimized for low voltage signal conditioning systems. A shutdown pin reduces supply current during standby conditions and thermal shutdown protects the part from overload conditions. The RH6200 maintains its pre-irradiation performance for supplies from 4.5V to 12.6V and is specified pre- and post-radiation at 5V and $\pm 5\text{V}$.

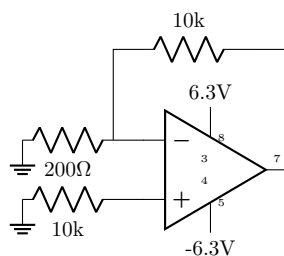
Total Supply Voltage (V^+ to V^-)	12.6V
Input Current (Note 2)	$\pm 40\text{mA}$
Output Short-Circuit Duration (Note 3)	Indefinite
Pin Current While Exceeding Supplies (Note 4)	$\pm 30\text{mA}$
Operating Junction Temperature Range (Note 5)	-55°C to 125°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

ABSOLUTE MAXIMUM RATINGS

(Note 1)

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BURN-IN CIRCUIT



RH6200M F01

PACKAGE/ORDER INFORMATION

ORDER PART NUMBER RH6200MW	TOP VIEW W PACKAGE 10-LEAD CERDIP
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TABLE 1: ELECTRICAL CHARACTERISTICS

Table 1: Table Fitted to Column Width												
SYMBOL	PARAMETER	CONDITIONS	NOTES	T _A = 25°C			SUB-GROUP	-55°C ≤ T _A ≤ 125°C			SUB-GROUP	UNITS
				MIN	TYP	MAX		MIN	TYP	MAX		
V _{OS}	Input Offset	V _S = 5V, 0V; V _{CM} = V ⁻ to V ⁺		0.6	2		1			4	2,3	mV
	Voltage	V _S = ±5V; V _{CM} = V ⁻ to V ⁺		2.5	6		1			9	2,3	mV
I _B	Input Bias Current	V _S = 5V, 0V; V _{CM} = V ⁺		8	18		1			20	2,3	μA
		V _S = 5V, 0V; V _{CM} = V ⁻		-50	-23		1		-100		2,3	μA